

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

TK380A65Y, ITK380A65Y

• FEATURES

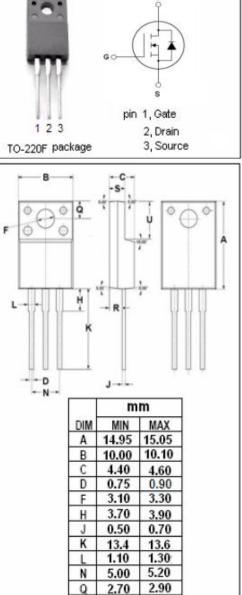
- Low drain-source on-resistance: $R_{DS}(ON) = 0.38\Omega$
- Enhancement mode: Vth = 3 to 4V (VDs = 10 V, ID=0.36mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

Switching Voltage Regulators

SYMBOL	PARAMETER	VALUE	UNIT			
V _{DSS}	Drain-Source Voltage	650	V			
V _{GS}	Gate-Source Voltage	±30	V			
ID	Drain Current-Continuous	9.7	А			
I _{DM}	Drain Current-Single Pulsed	38.8	А			
PD	Total Dissipation @Tc=25°C	30	W			
Tj	Max. Operating Junction Temperature	150	°C			
T _{stg}	Storage Temperature	-55~150	°C			

• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)



THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	4.16	°C /W
Rth(ch-a)	Channel-to-ambient thermal resistance	62.5	°C /W

1

R

s

U

2.20

6.40

2.40

2.90

6.60



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ELECTRICAL CHARACTERISTICS

 $T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	650			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = 10V; I _D =0.36mA	3		4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =4.9A			380	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 650V; V _{GS} = 0V			10	μA
V _{SDF}	Diode forward voltage	I _{DR} =9.7A, V _{GS} = 0 V			1.7	v

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2